

RADIAL BEAM **POWER TETRODE**

DESCRIPTION

The F-7213 is a metal and ceramic forced-air-cooled tetrode designed for use as a CW rf amplifier at frequencies up to 1215 MHz. Its uses include operation in compact aircraft, mobile and stationary equipment. It may be used as a linear rf power amplifier in single sideband suppressed carrier service, as a plate-modulated rf power amplifier in Class C telephony service, as an rf power amplifier and oscillator Class C telegraphy service and as an rf power amplifier in Class C FM telephony service. The unipotential cathode is of the oxide coated matrix type and the anode radiator assembly features integral brazed construction. Processing is especially rigorous and includes a double vacuum exhaust procedure that permits higher temperature degassing of internal elements.

Electrical Characteristics	Min.	Nom.	Max.
Heater Voltage (1)	16.3	5.5	6.0 Volts 18.2 Amp
Heater Starting Current	D TRANSITA		55 Amp
Cathode Warm Up Time	5		Minutes
(Ib=.020A Eb=3000V Ec2=1000V)			— 140 Volts
Screen Current	000		
(lb=.6A Eb=2500V Ec2=500V)	028		+.012 Amp
Amplification Factor (Grid-Screen)	8		24
Useful Power Output (2)	1000		Watts
Grid to Plate (3)			17 pf
Grid to Cathode-Heater	37		46 pf
Plate to Cathode-Heater (3 & 4)	37		.017 pf
Grid to Screen	14.6		62 pf
Screen to Plate Screen to Cathode-Heater (4)	14.6		17.8 pf 1.4 pf
Mechanical Characteristics			
Mounting Position	11111111	t t e t e t e t	Any
Type of Cooling			Forced Al
Maximum Plate Core and Seal Temperature (5)			250 0
Net Weight (approx.)			2 lbs
Vibration: Low Frequency (6)			500 mv max

Note 1. Under high frequency operating conditions, transit time effects will affect cathode temperature, the heater may be operated at the lowest voltage that will give stable performance.

High Frequency (7)

Note 2. Cathode driven CW amplifier under the following conditions: 600 MHz, D-C Plate Voltage 2,500 Volts, D-C Screen Voltage 700 Volts and D-C Grid Voltage adjusted for 1.0 ampere plate current.

Measured with an 8" OD, 3" ID flat metal shield located in the plane of and connected to the screen terminal.

Note 4. Measured with an 8" OD, 2%" ID flat metal shield located in the plane of and connected to the grid terminal.

Note 5. A temperature sensitive lacquer is convenient for this measurement.

Note 6. Per MIL-E-1E test method 1031 Ebb=450V Ec2=300V Ec/Ib=.010A Rp=2000ohms

Note 7. Per MIL-E-1E test method 1031

F-7213

RADIO FREQUENCY LINEAR AMPLIFIER CLASS AB₁
Single-sideband suppressed—carrier service (Peak envelope conditions for a signal having a minimum peak to average power ratio of 2)

Maximum CCS Ratings (8) D-C Voltage D-C Screen Voltage D-C Plate Current D-C Grid Current Plate Input Screen Input Plate Dissipation		up to 1215 MHz 3,000 Volts 1,000 Volts 1.0 Amp .2 Amp 2,500 Watts 50 Watts 1,500 Watts
		up to
Typical CCS Operation — Class AB _I single tone		60 MHz
D-C Plate Voltage	2,250	2,500 Volts
D-C Screen Voltage	700	700 Volts
D-C Grid Voltage	-50	-50 Volts
Max. Signal Plate Current	.9	1.0 Amp
Zero Signal Plate Current	.2	.2 Amp
Max. Signal Screen Current	.045	.045 Amp
Zero Signal Screen Current	0	0 Amp
Max. Signal Grid Current	0	0 Amp
Max. Signal Peak RF Grid Voltage	50	50 Volts
Max. Signal Driving Power (approx.)	0	0 Watts
Max. Signal Power Out (approx.)	1,000	1,250 Watts
Effective RF Load Resistance	1,100	1,100 ohms
Maximum Circuit Values — Grid circuit resistation.	ice und	er any condi-
Fixed Bias	5.00	00 Max. ohms
Fixed Bias (Class AB ₁)		ecommended
Cathode Bias		ecommended
Screen Circuit Impedance	NOT IN	Note 9
Plate Circuit Impedance		Note 10
Maximum Circuit Values		
Grid Circuit Resistance under any condition:		
With Fixed Bias.	500	0 Max. Ohms
With Fixed Bias (Class AB ₁)—		ecommended
With Cathode Bias		ecommended
Screen Circuit Impedance	1100111	Note 9
Plate Circuit Impedance		Note 10
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PLATE MODULATED RADIO FREQUENCY POWER AMPLIFIER Class C telephony (carrier conditions with maximum modulation factor of 1)

Maximum CCS Ratings (8)		1215	MHz
D-C Plate Voltage	2017/2017	2,500	Volts
D-C Screen Voltage		1,000	
D-C Grid Voltage		-300	
D-C Plate Current			Amp
D-C Grid Current			Amp
Plate Input		1.700	
Screen Input	0.000		Watts
Plate Dissipation		1.000	
			watts
Typical CCS Operation — Grid drive circuit at 60	0 MHz		
D-C Plate Voltage	1,800	2,000	Volts
D-C Screen Voltage	500	500	Volts
D-C Grid Voltage	-75	-75	Volts
D-C Plate Current	.75	.83	Amp
D-C Screen Current	.015	.015	
D-C Grid Current (approx.)	.04		Amp
Driver Power Output (approx.)	50		Watts
Useful Power Output (approx.)	650		Watts
Maximum Circuit Values			
Grid circuit resistance under any condition	721171	5,000	ohms

RADIO FREQUENCY POWER AMPLIFIER OR OSCILLATOR Class C telegraphy

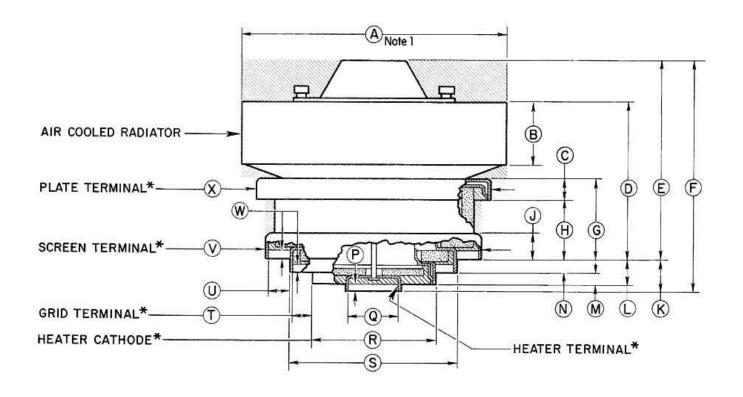
RADIO FREQUENCY POWER AMPLIFIER Class C FM telephony

Maximum CCC Datings (D)		up i	
Maximum CCS Ratings (8)		1215	
D-C Plate Voltage		3,000 \	
D-C Screen Voltage		1,000 \	olts/
D-C Grid Voltage		-300 V	olts.
D-C Plate Current		1.0 /	amp
D-C Grid Current	an region of the	0.2 /	
Plate Input	34.11800(A)4.129.	2,500 \	Natts
Screen Input		50 \	Natts
Plate Dissipation	execution.	1,500 \	Vatts
Typical CCS Operation — Grid drive circuit at 6	DO MHz		
D-C Plate Voltage	2,250	2,500 \	olts
D-C Screan Voltage	500	500 V	olts
D-C Grid Voltage	-75	-75 V	olts
D-C Plate Current	0.9	1.0 /	
D-C Screen Current	.02	.02 /	
D-C Grid Current (approx.)	.07	.07 4	
Output Circuit Efficiency (approx.)	90	90 9	
Driver Power Output (approx.)	70		Vatts
Useful Power Output (approx.)		1,350 \	
Maximum Circuit Values			
Grid circuit resistance under any condition		5,000	hms

aximum ratings are limiting values above which the serviceability of the tube may be impaired with respect to life and satisfactory performance and should not be exceeded under the worst probable conditions.

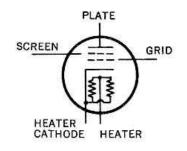
Note 9. The screen to ground impedance must be low enough to prevent build-up of screen voltage under negative current conditions.

Note 10. A plate impedance which will provide a plate-voltage-supply regulation of no better than 10% is recommended.



DIMENSIONAL DATA (IN INCHES)

DIM.	MIN.	MAX.
A Dia.	3.69	3.75
В	.850	
С	.22	
D	2.15	2.23
E	2.71	2.85
F	3.14	3.34
G	1.160	1.165
Н	.79	.85
J	.22	
K	.43	.49
L	.34	.40
M	.115	
N	.175	.225
P	.135	
Q Dia.		.725
R Dia.	1.710	
S Dia.	2.307	
T	.200	
U	.250	
V Dia.	3.010	
w	.105	
X Dia.	3.210	



Accessories Socket.....57282



HATCHED REGION NOTE 2



CERAMIC INSULATOR

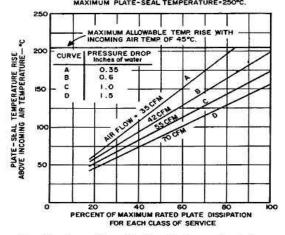
Note 1. Concentricity between the various diameters is such that the tube will enter a gauge having suitably spaced concentric apertures and posts of the following diameters:

and posts of the following diameters:	
A. Radiator Band	3.7805
B. Plate Terminal	3.2605
C. Screen Terminal	3.0605
D. Grid Terminal	2.3375
E. Heater-Cathode Terminal.	1.7445
F. Heater Terminal	0.6945

Note 2. Keep all hatched regions clear. Do not allow contacts or circuit components to protrude into these annular volumes. Diameters of hatched areas above Air-Cooled Radiator, Plate Terminal Contact Surface, and Screen Terminal Contact Surface shall not be greater than its associated diameter.

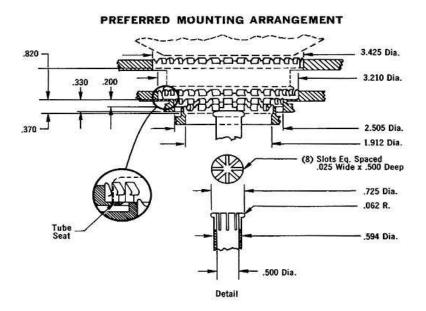
Zo = 5.9 OHMS GRID (G) to SCREEN (G2) GRID (G) to CATHODE (K) FREQUENCY - MHZ

TYPICAL COOLING CHARACTERISTICS AIR FLOW THROUGH RADIATOR IN EITHER DIRECTION MAXIMUM PLATE-SEAL TEMPERATURE=250°C.

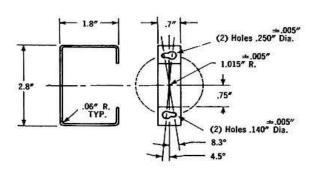


Standby Operation: Cooling Air is required when only heater voltage is applied to the tube.

Shutdown Operation: Air flow should continue for several minutes after all power to the tube is removed.

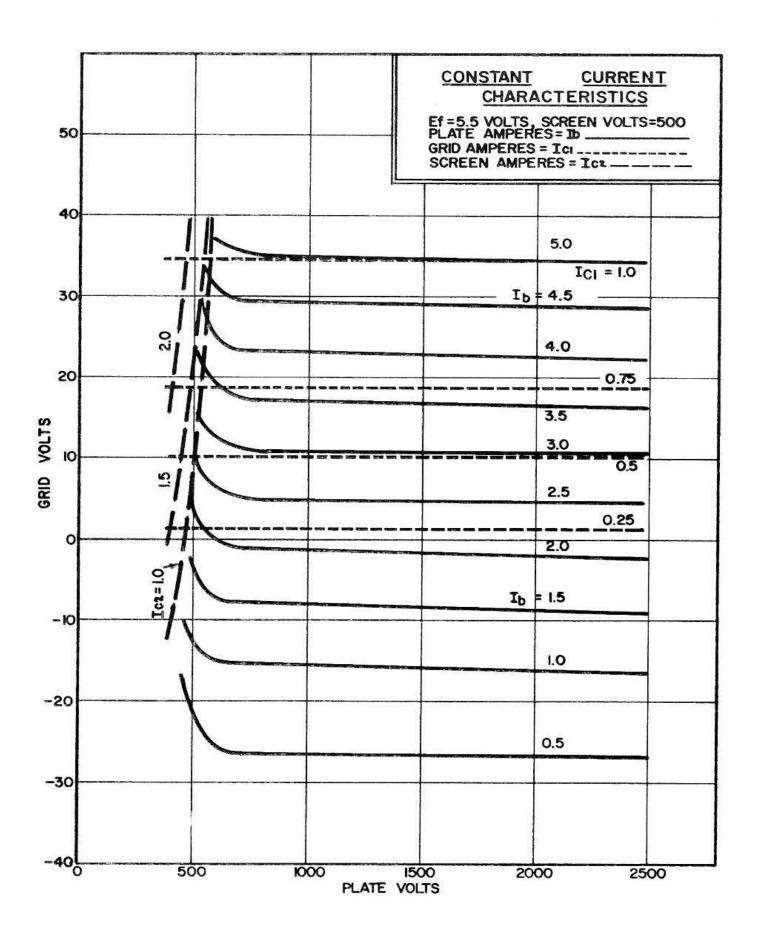


TUBE EXTRACTOR



- NOTES:
 1. Material ½s" thk. Cold
 Rolled Steel
 2. Slot Between Holes
 3. Round All Edges

ELECTRON TUBE DIVISION TTT



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